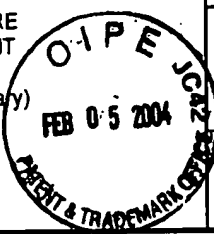


Form PTO-1449		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		ATTY. DOCKET NO. YOR920030075US1 (8728-613)		SERIAL NO. 10/643,307	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use several sheets if necessary)				APPLICANT Louis L. Hsu et al.			
				FILING DATE August 19, 2003		GROUP ART UNIT	



U.S. PATENT DOCUMENTS							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE

FOREIGN PATENT DOCUMENTS								
		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION	
							YES	NO

OTHER PRIOR ART (Including Author, Title, Date, Pertinent Pages, Etc.)			
<div style="font-family: cursive; font-size: 1.2em;">mw</div>			Hang Hu, et al., <u>A High Performance MIM Capacitor Using HfO₂ Dielectrics</u> , IEEE Electron Device Letters, Vol. 23, No. 9, September 2002, pp. 514-516.

EXAMINER <div style="font-family: cursive; font-size: 1.2em;">mWilczewski</div>	DATE CONSIDERED <div style="font-family: cursive; font-size: 1.2em;">6/2005</div>
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* EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

(Form PTO-1449 [6-4])